

## SOT-23 Plastic-Encapsulate Transistors

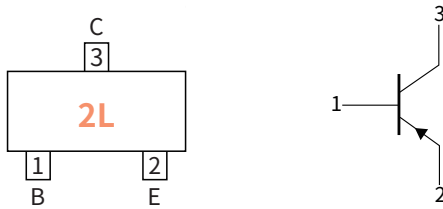
### Features

- Complementary to MMBT5551
- Power dissipation of 300mW
- High stability and high reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260°C

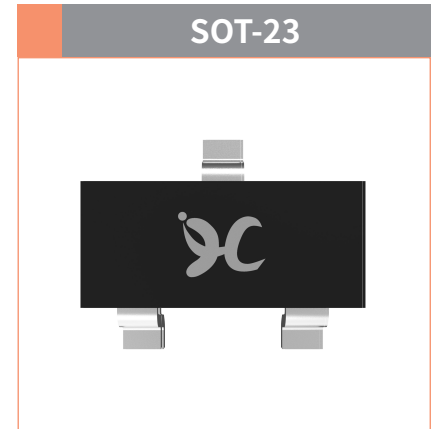
### Mechanical Data

- Case: SOT-23  
Molding compound meets UL 94V-0 flammability rating, RoHS-compliant, halogen-free
- Terminals: Solder plated, solderable per MIL-STD-750, Method 2026

### Function Diagram



**Collector-Base Voltage**  
VCBO -160V  
**Collector Current**  
-0.6 Ampere



### Maximum Ratings (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	VALUE
Collector-Base Voltage	$V_{CBO}$	V	-160
Collector-Emitter Voltage	$V_{CEO}$		-150
Emitter-Base Voltage	$V_{EBO}$		-5.0
Collector Current	$I_C$	A	-0.6
Collector Power Dissipation	$P_C$	mW	300
Storage temperature	$T_{stg}$	°C	-55 ~+150
Junction temperature	$T_j$	°C	-55 ~+150
Typical Thermal Resistance	$R_{\theta J-A}$	°C /W	417

### Electrical Characteristics (Ta=25°C Unless otherwise noted)

PARAMETER	SYMBOL	UNIT	Condition	Min	Max
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	V	$I_C = -100\mu A, I_E = 0$	-160	—
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$		$I_C = -1.0mA, I_B = 0$	-150	—
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$		$I_E = -10\mu A, I_C = 0$	-5.0	—
Collector-Base cut-off current	$I_{CBO}$	nA	$V_{CB} = -120V, I_B = 0$	—	-100
Emitter-Base cut-off current	$I_{EBO}$		$V_{EB} = -4.0V, I_C = 0$	—	-100
DC Current Gain	$h_{FE}$	—	$I_C = -1.0mA, V_{CE} = -5.0V$	80	—
			$I_C = -10mA, V_{CE} = -5.0V$	100	300
			$I_C = -50mA, V_{CE} = -5.0V$	30	—
Collector-Emitter Saturation Voltage	$V_{CE(sat)1}$	V	$I_C = -10mA, I_B = -1.0mA$	—	-0.2
Collector-Emitter Saturation Voltage	$V_{CE(sat)2}$		$I_C = -50mA, I_B = -5.0mA$	—	-0.5
Base-Emitter Saturation Voltage	$V_{BE(sat)1}$		$I_C = -10mA, I_B = -1.0mA$	—	-1.0
Base-Emitter Saturation Voltage	$V_{BE(sat)2}$		$I_C = -50mA, I_B = -5.0mA$	—	-1.0

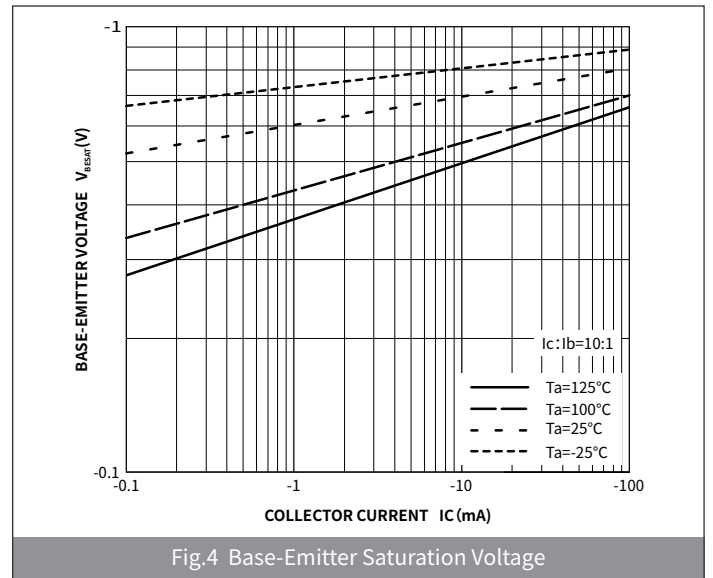
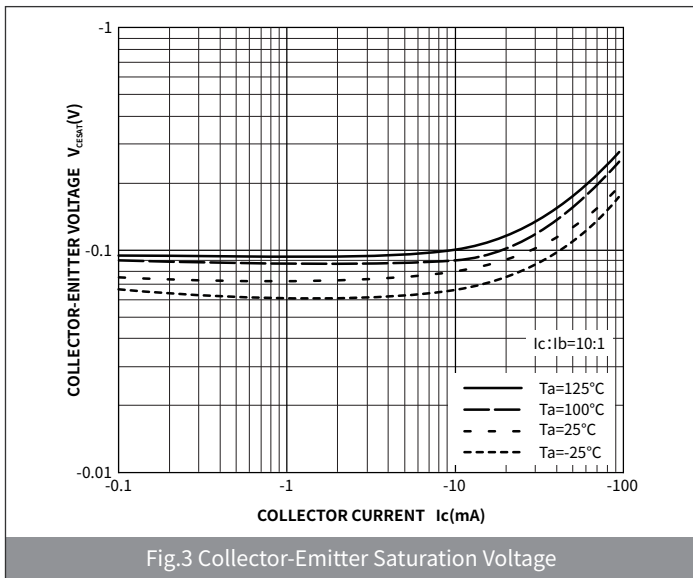
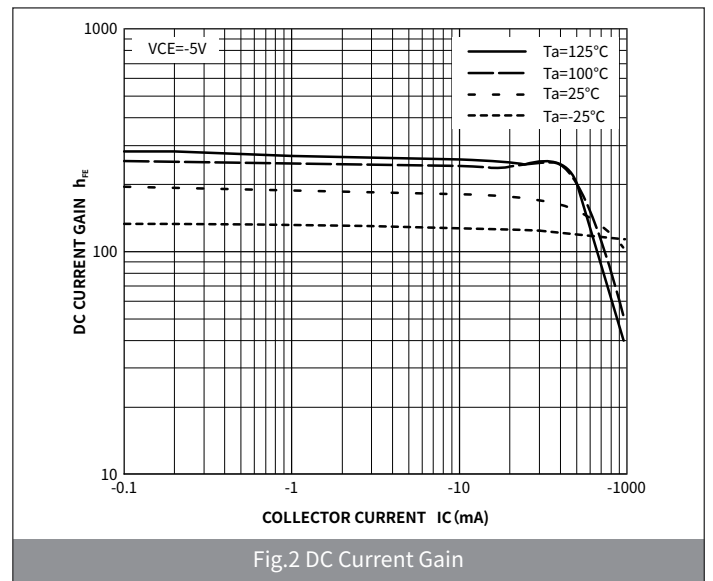
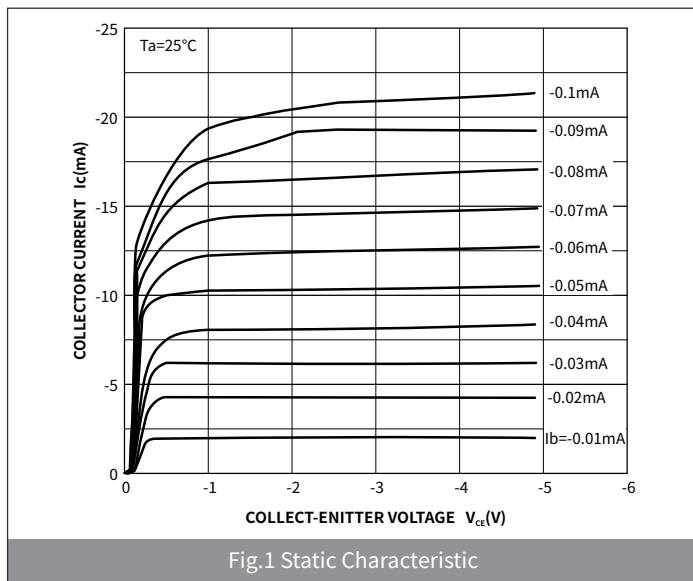
## ● Small-signal Characteristics

ITEM	SYMBOL	Condition	UNIT	Min	Max
Transition frequency	$f_T$	$I_C = 10\text{mA}, V_{CE} = -5.0\text{V}, f = 30\text{MHz}$	MHz	100	—

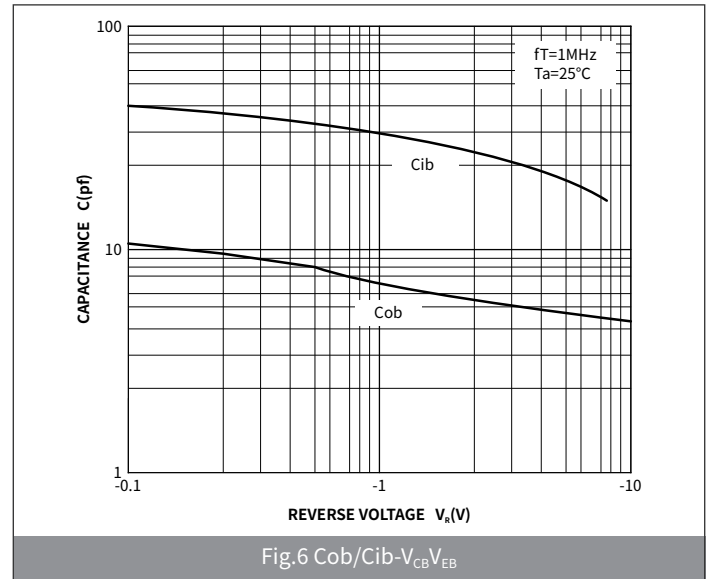
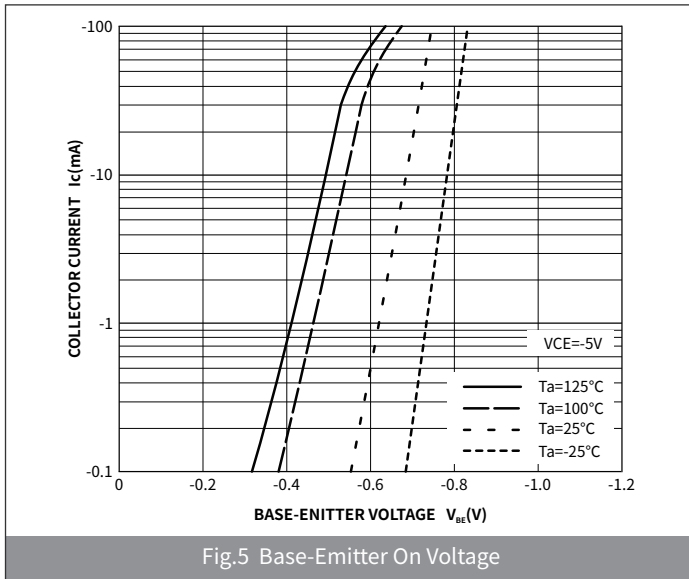
## ● Ordering Information

PACKAGE	PACKAGE CODE	UNIT WEIGHT(g)	REEL(pcs)	BOX(pcs)	CARTON(pcs)	DELIVERY MODE
SOT-23	R1	0.008	3000	30000	120000	7"

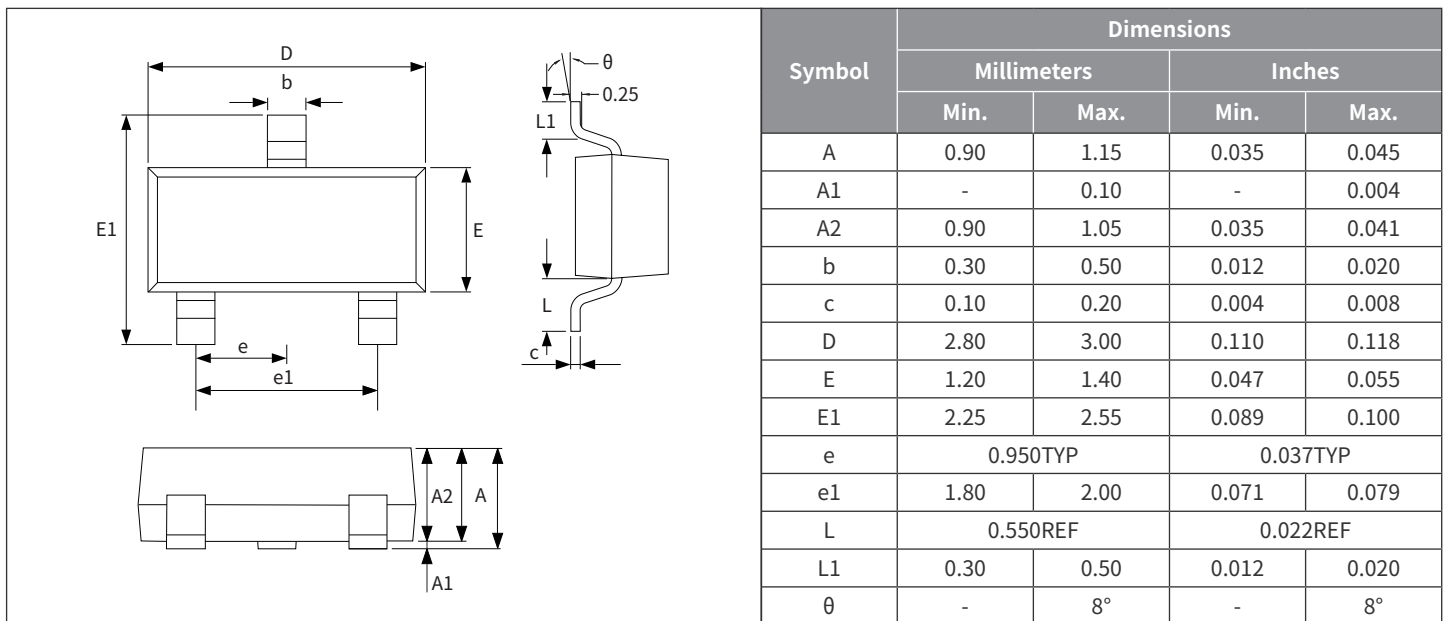
## ● Ratings And Characteristics Curves (Ta=25°C Unless otherwise specified)



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## ● Package Outline Dimensions (SOT-23)



## ● Suggested Pad Layout

